

isc N-Channel MOSFET Transistor

AOB482L

FEATURES

- Drain Current –I_D=105A@ T_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage-: V_{DSS}=80V(Min)
- Static Drain-Source On-Resistance
- : $R_{DS(on)} = 6.9m \Omega$ (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

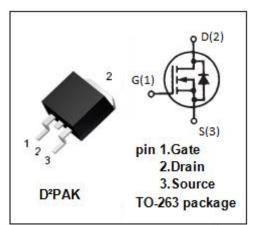
• Designed for use in switch mode power supplies and general purpose applications.

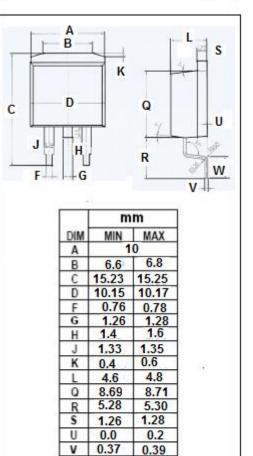
SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	80	V
V_{GS}	Gate-Source Voltage-Continuous	±25	V
ID	Drain Current-Continuous	105	А
I _{DM}	Drain Current-Single Pluse	330	А
P _D	Total Dissipation @T _c =25℃	333	W
TJ	Max. Operating Junction Temperature -55~175		°C
T _{stg}	Storage Temperature	-55~175	°C

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0.45	°C/W





isc website: www.iscsemi.com

W

2.80

2.82



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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	80		V
V _{GS} (th)	Gate Threshold Voltage	V_{DS} = V_{GS} ; I_D = 0.25mA	2.5	3.7	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =20A		6.9	mΩ
lgss	Gate-Body Leakage Current	V _{GS} = ±25V;V _{DS} = 0		±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 80V; V _{GS} = 0 V _{DS} = 80V; V _{GS} = 0@T _J =55°C		10 50	μA
V _{SD}	Forward On-Voltage	I _S = 1A; V _{GS} = 0		1	V

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